Search History

L Number	Hits	Search Text	DB	Time stamp
1	322122	nonvolatile or eeprom or flash	USPAT; US-PGPUB;	2004/10/28 12:33
			EPO; JPO; DERWENT; IBM_TDB	
2	52785	wordline or "word line"	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/28
3	58362	bitline or "bit line"	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28 12:34
4	1653029	writ\$4 or program\$4	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/10/28 12:35
5	34113	simultan\$7 near5 (writ\$4 or program\$4)	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/10/28 12:35
6	21529	select\$5 near5 (wordline or "word line")	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/10/28 12:36
7	127672	first near2 voltage	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28 12:36
8	117680	second near2 voltage	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28
10	172577	reference near2 voltage	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28
11	89705	pulse near3 voltage	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28 12:37
12	14756	(nonvolatile or eeprom or flash) and (wordline or "word line")	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28
13	10887	((nonvolatile or eeprom or flash) and (wordline or "word line")) and (bitline or "bit line")	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/10/28 12:37
14 .	9719	(((nonvolatile or eeprom or flash) and (wordline or "word line")) and (bitline or "bit line")) and (writ\$4 or program\$4)	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/28 12:38
			IBM TDB	

15	1680	((((nonvolatile or eeprom or flash) and	USPAT;	2004/10/28
	1	(wordline or "word line")) and (bitline	US-PGPUB;	12:38
		or "bit line")) and (writ\$4 or	EPO; JPO;	
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
		or program\$4))	IBM TDB	
16	1285	(((((nonvolatile or eeprom or flash) and	USPAT;	2004/10/28
10	1203	(wordline or "word line")) and (bitline	US-PGPUB;	12:38
		or "bit line")) and (writ\$4 or	EPO; JPO;	12.30
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
		or program\$4))) and (select\$5 near5	IBM TDB	
		(wordline or "word line"))	1011_100	
17	587	((((((nonvolatile or eeprom or flash) and	USPAT;	2004/10/28
1,	307	(wordline or "word line")) and (bitline	US-PGPUB;	12:38
		or "bit line")) and (writ\$4 or	EPO; JPO;	12.30
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
		or program\$4))) and (select\$5 near5	IBM TDB	
	1	(wordline or "word line"))) and (first	IBM_IBB	
		near2 voltage)		
18	496		USPAT;	2004/10/28
10	450	and (wordline or "word line")) and	US-PGPUB;	12:38
		(bitline or "bit line")) and (writ\$4 or	EPO; JPO;	12.30
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
		or program\$4))) and (select\$5 near5	IBM TDB	
		(wordline or "word line"))) and (first	1511_155	
		near2 voltage)) and (second near2		
		voltage)		•
19	232	1	USPAT;	2004/10/28
10	232	and (wordline or "word line")) and	US-PGPUB;	12:38
		(bitline or "bit line")) and (writ\$4 or	EPO; JPO;	12.50
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
	1	or program\$4))) and (select\$5 near5	IBM TDB	
		(wordline or "word line"))) and (first	1011_100	
		near2 voltage)) and (second near2		
		voltage)) and (reference near2 voltage)		
20	63		USPAT;	2004/10/28
20		and (wordline or "word line")) and	US-PGPUB;	12:38
		(bitline or "bit line")) and (writ\$4 or	EPO; JPO;	12.50
		program\$4)) and (simultan\$7 near5 (writ\$4	DERWENT;	
		or program\$4))) and (select\$5 near5	IBM TDB	
		(wordline or "word line"))) and (first	1211_122	3
		near2 voltage)) and (second near2		·
		voltage)) and (reference near2 voltage))		
	ľ	and (pulse near3 voltage)		
		(F 110410 1010490)	<u> </u>	L